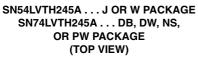
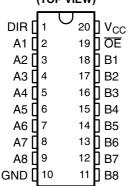
SN54LVTH245A, SN74LVTH245A 3.3-V ABT OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

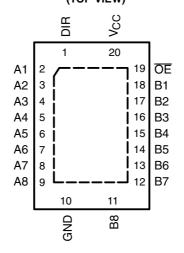
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- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Support Unregulated Battery Operation Down to 2.7 V
- I_{off} and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

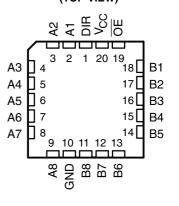




SN74LVTH245A . . . RGY PACKAGE (TOP VIEW)



SN54LVTH245A . . . FK PACKAGE (TOP VIEW)



description/ordering information

These octal bus transceivers are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

ORDERING INFORMATION

T _A	PACKAGE	t	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	SN74LVTH245ARGYR	LXH245A
	COIC DW	Tube	SN74LVTH245ADW	LVTHOAFA
	SOIC - DW	Tape and reel	SN74LVTH245ADWR	LVTH245A
	SOP - NS	Tape and reel	SN74LVTH245ANSR	LVTH245A
-40°C to 85°C	SSOP – DB	Tape and reel	SN74LVTH245ADBR	LXH245A
	TOOOD DW	Tube	SN74LVTH245APW	L VI I 0 45 A
	TSSOP – PW	Tape and reel	SN74LVTH245APWR	LXH245A
	VFBGA – GQN	Towns and made	SN74LVTH245AGQNR	L VI I 0 45 A
	VFBGA – ZQN (Pb-free)	Tape and reel	SN74LVTH245AZQNR	LXH245A
	CDIP – J	Tube	SNJ54LVTH245AJ	SNJ54LVTH245AJ
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH245AW	SNJ54LVTH245AW
	LCCC – FK	Tube	SNJ54LVTH245AFK	SNJ54LVTH245AFK

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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description/ordering information (continued)

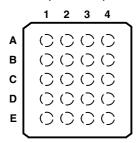
These devices are designed for asynchronous communication between data buses. They transmit data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the devices so the buses are effectively isolated.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

SN74LVTH245A . . . GQN OR ZQN PACKAGE (TOP VIEW)



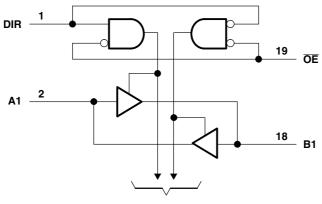
terminal assignments

	1	2	3	4
Α	A1	DIR	V_{CC}	ŌĒ
В	А3	B2	A2	B1
С	A 5	A4	B4	B3
D	A7	B6	A6	B5
Е	GND	A8	B8	B7

FUNCTION TABLE

INP	UTS	ODEDATION
ŌĒ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Χ	Isolation

logic diagram (positive logic)



To Seven Other Channels

Pin numbers shown are for the DB, DW, FK, J, NS, PW, RGY, and W packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)	–0.5 V to V _{CC} + 0.5 V
Current into any output in the low state, I _O : SN54LVTH245A	96 mA
SN74LVTH245A	128 mA
Current into any output in the high state, I _O (see Note 2): SN54LVTH245A	48 mA
SN74LVTH245A	64 mA
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ_{JA} (see Note 3): DB package	70°C/W
(see Note 3): DW package	58°C/W
(see Note 3): GQN/ZQN package	78°C/W
(see Note 3): NS package	60°C/W
(see Note 3): PW package	83°C/W
(see Note 4): RGY package	37°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.

recommended operating conditions (see Note 5)

			SN54LVT	H245A	SN74LVT	UNIT	
			MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage	2.7	3.6	2.7	3.6	V	
V _{IH}	High-level input voltage	2		2		V	
V _{IL}	Low-level input voltage		0.8		0.8	V	
VI	Input voltage		5.5		5.5	V	
I _{OH}	High-level output current			-24		-32	mA
I _{OL}	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T _A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 5: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SN54LVTH245A, SN74LVTH245A 3.3-V ABT OCTÁL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAI	DAMETER	TECT O	ONDITIONS	SN5	4LVTH2	45A	SN7	4LVTH2	45A	UNIT
PAI	RAMETER	TEST C	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNII
V _{IK}		$V_{CC} = 2.7 \text{ V},$	$I_I = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100 \mu A$	V _{CC} -0.	2		V _{CC} -0.	2		
, ,		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4	2.4		V
V _{OH}		V 0.V	$I_{OH} = -24 \text{ mA}$	2						V
		V _{CC} = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		V _{CC} = 2.7 V	$I_{OL} = 100 \mu\text{A}$			0.2			0.2	
		V _{CC} = 2.7 V	$I_{OL} = 24 \text{ mA}$			0.5			0.5	
l ,,			I _{OL} = 16 mA			0.4			0.4	٧
V _{OL}		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V
	V _{CC} = 3 V	$I_{OL} = 48 \text{ mA}$			0.55					
			$I_{OL} = 64 \text{ mA}$						0.55	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	$V_{I} = 5.5 \text{ V}$			10			10	
l _i	I _I A or B ports [‡]		$V_{I} = 5.5 \text{ V}$			20	20 20			
		V _{CC} = 3.6 V	V _I = V _{CC} 1					1	,	
			$V_I = 0$			-5			-5	
I _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V						±100	μΑ
		V _{CC} = 3 V	$V_{I} = 0.8 V$	75			75			
I _{I(hold)}	A or B ports	vCC = 3 v	V _I = 2 V	-75			-75			μA
-i(noid)	Troi 2 ponto	V _{CC} = 3.6 V [§] ,	V _I = 0 to 3.6 V			500 -750		į.		
I _{OZPU}		$V_{CC} = 0$ to 1.5 V, $V_O = 0$ $\overline{OE} = \text{don't care}$	0.5 V to 3 V,			±100*			±100	μА
I _{OZPD}		V_{CC} = 1.5 V to 0, V_{O} = \overline{OE} = don't care	0.5 V to 3 V,			±100*			±100	μΑ
		V _{CC} = 3.6 V,	Outputs high			0.19			0.19	
I _{CC}		$I_{O} = 0$,	Outputs low			5	5		mA	
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19	
Δl _{CC} ¶		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, One input at } V_{CC} - 0.6 \text{ V,}$ Other inputs at V_{CC} or GND		0.2	mA					
C _i		V _I = 3 V or 0			4			4		pF
C _{io}		V _O = 3 V or 0			9			9		pF

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



 $^{^{\}dagger}$ All typical values are at V_{CC} = 3.3 V, T_{A} = 25°C.

[‡] Unused terminals are at V_{CC} or GND.

[§] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

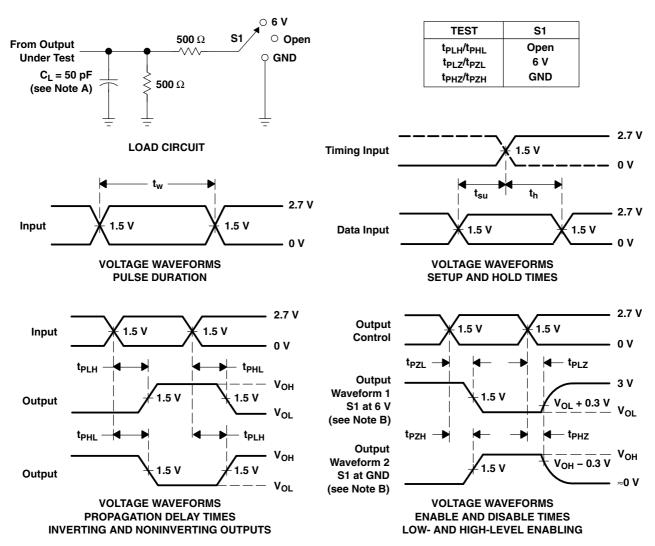
This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

			;	SN54LVTH245A				SN7	4LVTH2	45A		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 3.3 V \pm 0.3 V		V _{CC} = 2.7 V		V_{CC} = 3.3 V \pm 0.3 V			V _{CC} = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX	
t _{PLH}	A - :: B	D or A	0.7	3.7		4.2	1.2	2.3	3.5		4	
t _{PHL}	A or B	B or A	0.7	3.7		4.2	1.2	2.1	3.5		4	ns
t _{PZH}	ŌĒ	A or D	1.2	5.7		7.4	1.3	3.2	5.5		7.1	20
t _{PZL}	OE	A or B	1.6	5.7		6.8	1.7	3.4	5.5		6.5	ns
t _{PHZ}	ŌĒ		1.8	6.2		6.8	2.2	3.5	5.9		6.5	
t _{PLZ}	SE	A or B	1.8	5.3		5.5	2.2	3.4	5		5.1	ns

 $^{^{\}dagger}$ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{Q} = 50 Ω , $t_{r} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
5962-9564201Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9564201Q2A SNJ54LVTH 245AFK
5962-9564201QRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9564201QR A SNJ54LVTH245AJ
5962-9564201QSA	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9564201QS A SNJ54LVTH245AW
5962-9564201V2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9564201V2A SNV54LVTH 245AFK
5962-9564201VRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9564201VR A SNV54LVTH245AJ
5962-9564201VSA	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9564201VS A SNV54LVTH245AW
SN74LVTH245ADBR	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245ADBR.B	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245ADBR1G4.B	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245ADW	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ADW.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ADWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ADWR.B	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ADWRG4	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ANS.B	Active	Production	SOP (NS) 20	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ANSR	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ANSR.B	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245ANSRG4.B	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A
SN74LVTH245APW	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A



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Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74LVTH245APW.B	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245APWE4	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245APWG4	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245APWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245APWR.B	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245APWRE4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245APWRG4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245APWRG4.B	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A
SN74LVTH245ARGYR	Active	Production	VQFN (RGY) 20	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LXH245A
SN74LVTH245ARGYR.B	Active	Production	VQFN (RGY) 20	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LXH245A
SN74LVTH245ARGYRG4.B	Active	Production	VQFN (RGY) 20	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LXH245A
SNJ54LVTH245AFK	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9564201Q2A SNJ54LVTH 245AFK
SNJ54LVTH245AJ	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9564201QR A SNJ54LVTH245AJ
SNJ54LVTH245AW	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9564201QS A SNJ54LVTH245AW

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

PACKAGE OPTION ADDENDUM

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54LVTH245A, SN54LVTH245A-SP, SN74LVTH245A:

● Catalog: SN74LVTH245A, SN54LVTH245A

Enhanced Product: SN74LVTH245A-EP, SN74LVTH245A-EP

Military: SN54LVTH245A

Space : SN54LVTH245A-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH245ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH245ADWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74LVTH245ANSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVTH245APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LVTH245APWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LVTH245ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH245ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LVTH245ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH245ANSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74LVTH245APWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74LVTH245APWRG4	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74LVTH245ARGYR	VQFN	RGY	20	3000	356.0	356.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9564201Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9564201V2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9564201VSA	W	CFP	20	25	506.98	26.16	6220	NA
SN74LVTH245ADW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH245ADW.B	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH245ANS.B	NS	SOP	20	40	530	10.5	4000	4.1
SN74LVTH245APW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVTH245APW.B	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVTH245APWE4	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVTH245APWG4	PW	TSSOP	20	70	530	10.2	3600	3.5
SNJ54LVTH245AFK	FK	LCCC	20	55	506.98	12.06	2030	NA

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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